

# MITSUBISHI THYRISTOR MODULES

## TM130DZ/CZ/PZ-M,-H

**HIGH POWER GENERAL USE  
INSULATED TYPE**

### TM130DZ/CZ/PZ-M,-H



(DZ Type)

- **IT (AV)** Average on-state current ..... **130A**
- **VRRM** Repetitive peak reverse voltage  
..... **400/800V**
- **VDRM** Repetitive peak off-state voltage  
..... **400/800V**
- **DOUBLE ARMS**
- **Insulated Type**
- **UL Recognized**

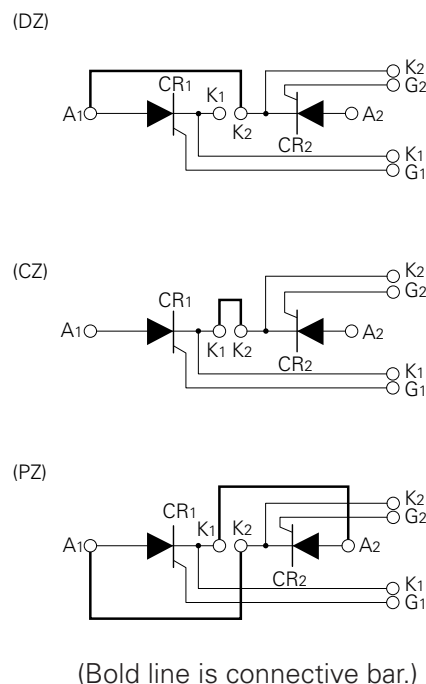
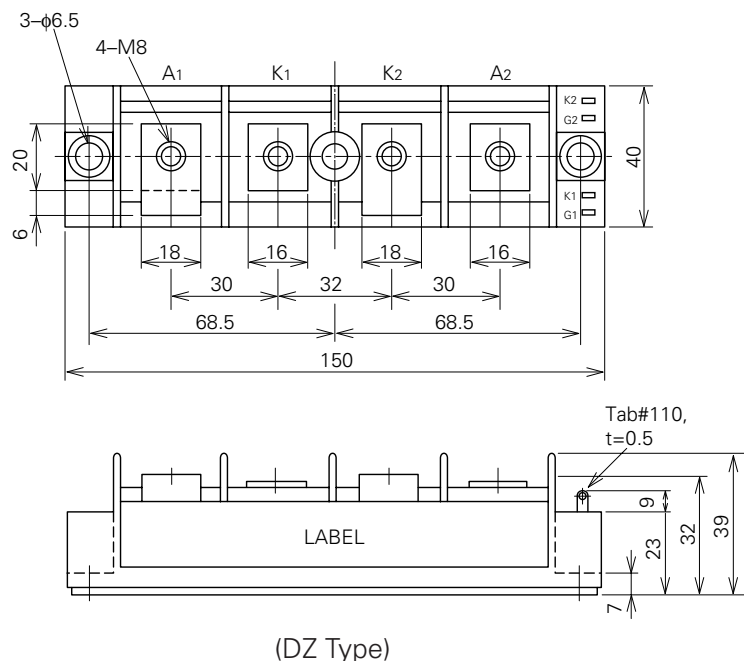
Yellow Card No. E80276 (N)  
File No. E80271

### APPLICATION

DC motor control, NC equipment, AC motor control, Contactless switches,  
Electric furnace temperature control, Light dimmers

### OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		M	H	
VRRM	Repetitive peak reverse voltage	400	800	V
VRSM	Non-repetitive peak reverse voltage	480	960	V
VR (DC)	DC reverse voltage	320	640	V
VDRM	Repetitive peak off-state voltage	400	800	V
VDSM	Non-repetitive peak off-state voltage	480	960	V
VD (DC)	DC off-state voltage	320	640	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current		205	A
IT (AV)	Average on-state current	Single-phase, half-wave 180° conduction, Tc=85°C	130	A
ITSM	Surge (non-repetitive) on-state current	One half cycle at 60Hz, peak value	2600	A
I <sup>2</sup> t	I <sup>2</sup> t for fusing	Value for one cycle of surge current	2.8 × 10 <sup>4</sup>	A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current	V <sub>D</sub> =1/2V <sub>DRM</sub> , I <sub>G</sub> =1.0A, T <sub>j</sub> =125°C	100	A/μs
PGM	Peak gate power dissipation		10	W
PG (AV)	Average gate power dissipation		3.0	W
VFGM	Peak gate forward voltage		10	V
VRGM	Peak gate reverse voltage		5.0	V
IFGM	Peak gate forward current		4.0	A
T <sub>j</sub>	Junction temperature		-40~+125	°C
T <sub>stg</sub>	Storage temperature		-40~+125	°C
V <sub>iso</sub>	Isolation voltage	Charged part to case	2500	V
—	Mounting torque	Main terminal screw M8	8.83~10.8	N·m
			90~110	kg·cm
		Mounting screw M6	1.96~3.92	N·m
			20~40	kg·cm
—	Weight	Typical value	300	g

## ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	T <sub>j</sub> =125°C, VRRM applied	—	—	30	mA
IDRM	Repetitive peak off-state current	T <sub>j</sub> =125°C, VDRM applied	—	—	30	mA
V <sub>TM</sub>	On-state voltage	T <sub>j</sub> =125°C, I <sub>TM</sub> =390A, instantaneous meas.	—	—	1.3	V
dv/dt	Critical rate of rise of off-state voltage	T <sub>j</sub> =125°C, V <sub>D</sub> =2/3V <sub>DRM</sub>	500	—	—	V/μs
V <sub>GT</sub>	Gate trigger voltage	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, R <sub>L</sub> =2Ω	—	—	3.0	V
V <sub>GD</sub>	Gate non-trigger voltage	T <sub>j</sub> =125°C, V <sub>D</sub> =1/2V <sub>DRM</sub>	0.25	—	—	V
I <sub>GT</sub>	Gate trigger current	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, R <sub>L</sub> =2Ω	15	—	100	mA
R <sub>th (j-c)</sub>	Thermal resistance	Junction to case (per 1/2 module)	—	—	0.22	°C/W
R <sub>th (c-f)</sub>	Contact thermal resistance	Case to fin, conductive grease applied (per 1/2 module)	—	—	0.1	°C/W
—	Insulation resistance	Measured with a 500V megohmmeter between main terminal and case	10	—	—	MΩ

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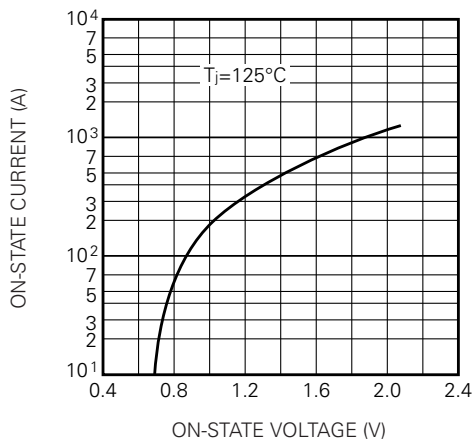
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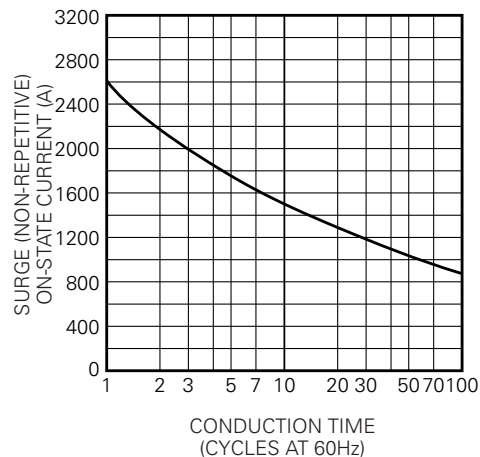
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PERFORMANCE CURVES

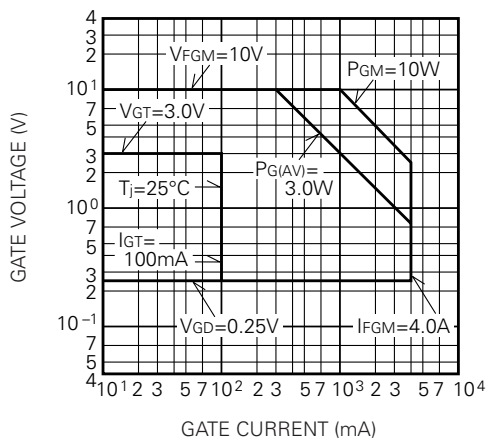
MAXIMUM ON-STATE CHARACTERISTIC



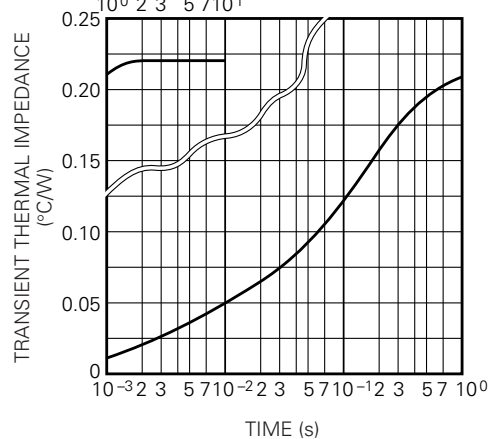
RATED SURGE (NON-REPETITIVE) ON-STATE CURRENT



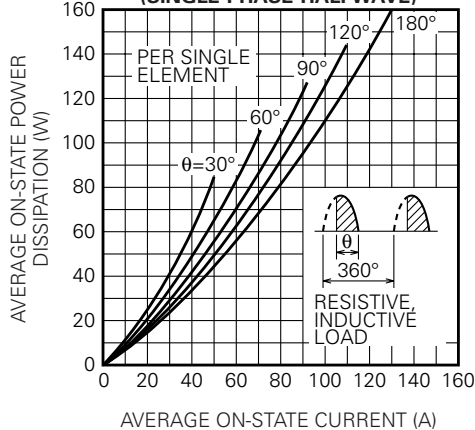
GATE CHARACTERISTICS



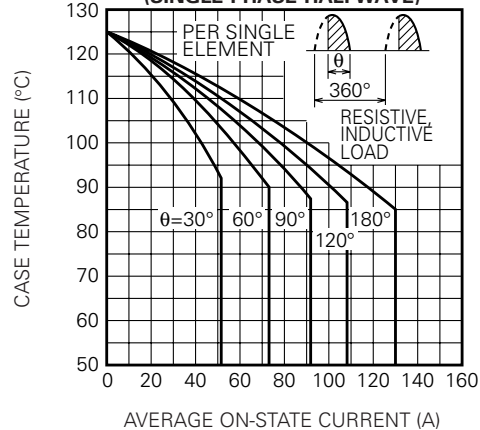
MAXIMUM TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)



MAXIMUM AVERAGE ON-STATE POWER DISSIPATION (SINGLE PHASE HALF WAVE)



LIMITING VALUE OF THE AVERAGE ON-STATE CURRENT (SINGLE PHASE HALF WAVE)

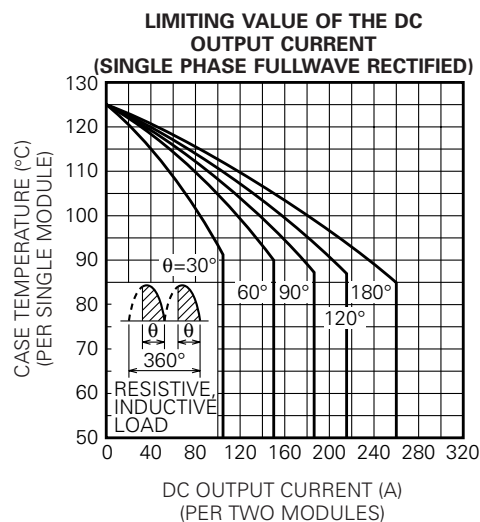
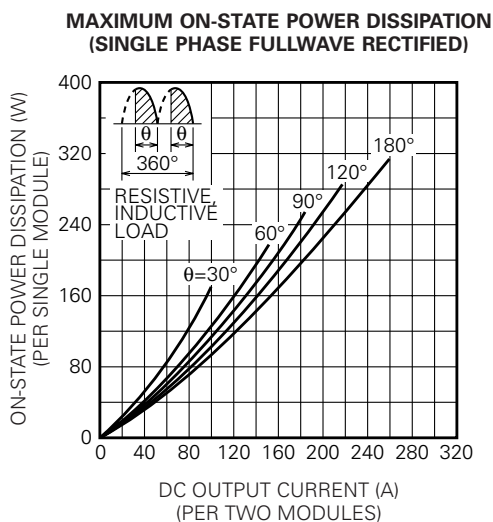
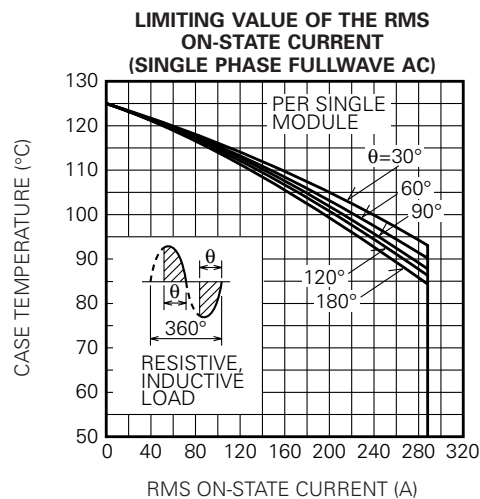
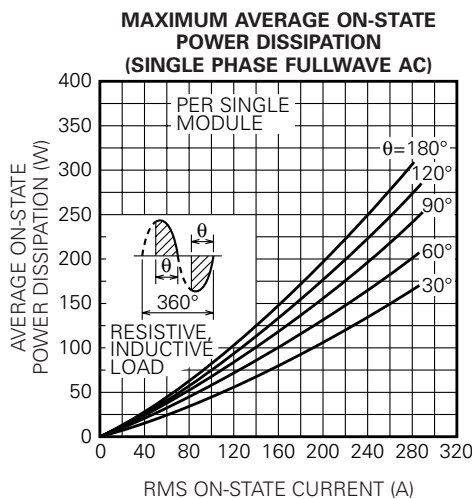
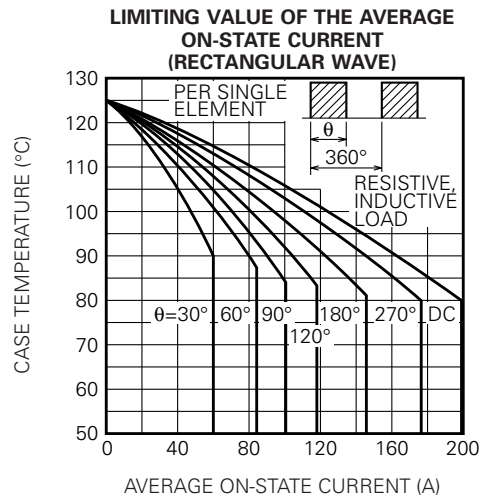
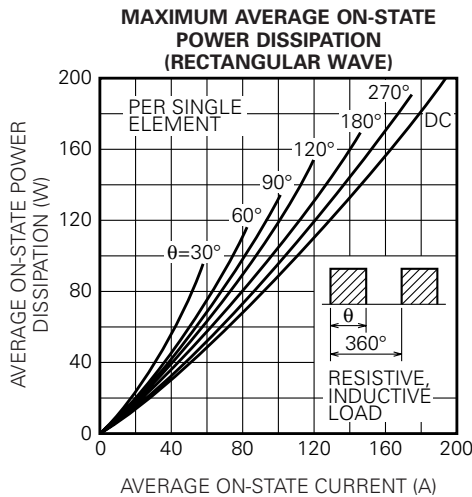


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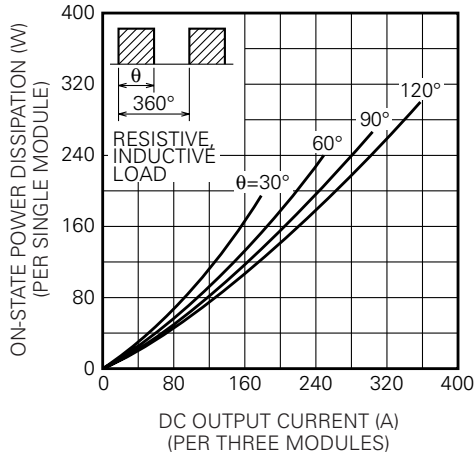


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MAXIMUM ON-STATE POWER DISSIPATION  
(THREE PHASE FULLWAVE RECTIFIED)



LIMITING VALUE OF THE DC OUTPUT CURRENT  
(THREE PHASE FULLWAVE RECTIFIED)

